

 $1700V 900m\Omega$ Silicon Carbide Power MOSFET N-Channel Enhancement Mode Features

• High blocking voltage with low on-resistance

- High-speed switching with low capacitances
- $12V..18V / 0VV_{GS}$ compatible with most flyback controllers
- Ultra-low drain-gate capacitance
- Qualified to operate under high humidity and high temperature environmental conditions
- Halogen free, RoHS compliant

Benefits

- Smooth switching waveforms
- Reduce switching losses and minimize gate ringing
- Higher system efficiency
- Increases system switching frequency
- Increases system reliability

Typical Applications

- Auxillary power supplies
- Switch Mode Power Supplies
- High-Voltage capacitive loads

Package



Orderable Part Number	Package	Marking		
C3M0900170J-TR	TO-263-7L	C3M0900170J		

Symbol Min. Unit Conditions Parameter Тур. Max Note Drain - Source Voltage 1700 $T_c = 25^{\circ}C$ V_{DS} -8 Maximum Gate - Source Voltage (Transient) +20 Transient V_{GS(max)} V **Operational Turn-On Gate-Source Voltage** +12...+18 Static **Operational Turn-Off Gate-Source Voltage** -4...0 4.4 $V_{GS} = 15 \text{ V}, T_{C} = 25 \text{ °C}, T_{J} \le 175 \text{ °C}$ DC Continuous Drain Current Note 2 I_{D} 3.3 $V_{GS} = 15 \text{ V}, T_{C} = 100 \text{ °C}, T_{I} \le 175 \text{ °C}$ А t_{Pmax} limited by T_{imax} **Pulsed Drain Current** \mathbf{I}_{DM} 15 Fig. 22 $V_{cc} = 15V, T_{c} = 25^{\circ}C$ $T_c = 25^{\circ}C, T_1 = 175^{\circ}C$ **Power Dissipation** P_{D} 41 W Fig. 20 -55 to **Operating Junction and Storage Temperature** T_J, T_{stg} +175 °C 260 Solder Temperature T,

Note (1): Review application Note PRD-04814 for additional details Note (2): Verified by design

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Key Parameters



Electrical Characteristics ($T_c = 25$ °C unless otherwise specified)

Symbol	Parameter	Min.	Тур.	Max.	Unit	Test Conditions	Note
$V_{(BR)DSS}$	Drain-Source Breakdown Voltage	1700			V	$V_{GS} = 0 V, I_D = 100 \mu A$	
V _{GS(th)} Gate Threshold Voltage		1.8	3.1	4.2	V	$V_{DS} = V_{GS}$, $I_D = 0.55$ mA	
		2.6		V	$V_{DS} = V_{GS}, I_D = 0.55 \text{ mA}, T_J = 175^{\circ}\text{C}$	Fig. 11	
I _{DSS}	Zero Gate Voltage Drain Current		1	50	μA	$V_{\text{DS}} = 1700 \text{ V}, V_{\text{GS}} = 0 \text{ V}$	
I _{GSS}	Gate-Source Leakage Current		10	250	nA	$V_{GS} = 15 V, V_{DS} = 0 V$	
R _{DS(on)}	Drain-Source On-State Resistance		900	1250	mΩ	$V_{GS} = 15 \text{ V}, I_D = 1.99 \text{ A}$	Fig. 4, 5, 6
DS(on)			1938		11132	$V_{GS} = 15 \text{ V}, I_D = 1.99 \text{ A}, T_J = 175^{\circ}\text{C}$	
g fs	Transconductance		1		s	V _{DS} = 20 V, I _{DS} = 1.99 A	Fig. 7
3.5			1			V_{DS} = 20 V, I_{DS} = 1.99 A, T_J = 175°C	
C _{iss}	Input Capacitance		202				
C _{oss}	Output Capacitance		8		pF	V_{GS} = 0 V, V_{DS} = 0V to 1200 V	Fig. 17 18
C _{rss}	Reverse Transfer Capacitance		1.4			F = 100 kHz Vac = 25 mV	
Eoss	Coss Stored Energy		8		μJ	- Vac = 25 mV	Fig. 16
C _{o(er)}	Effective Output Capacitance (Energy Related)		10		pF		Note: 3
C _{o(tr)}	Effective Output Capacitance (Time Related)		13		pF	$V_{GS} = 0 V, V_{DS} = 0V \text{ to } 1200V$	
E _{ON}	Turn-On Switching Energy (External Diode)		128			V_{DS} = 1200 V, V_{GS} = -4 V/15 V, I_D = 1.99 A,	
EOFF	Turn Off Switching Energy (External Diode)		13		μJ	$R_{G(ext)} = 2.5 \Omega$, L= 1707 μH, T _J = 175°C FWD = External SiC DIODE	Fig. 26, 28
t _{d(on)}	Turn-On Delay Time		20			$V_{DD} = 1200 \text{ V}, \text{ V}_{GS} = -4 \text{ V}/15 \text{ V}$	1
t,	Rise Time			$I_D = 1.99 \text{ A}, R_{G(ext)} = 2.5 \Omega, Tj=175^{\circ}C,$	Fig. 27		
$t_{d(off)}$	Turn-Off Delay Time		20		ns	ns L=1707 μH Timing relative to V _{ps}	
t _f	Fall Time		42		1	Inductive load	
$R_{G(int)}$	Internal Gate Resistance		31		Ω	$f = 1 MHz$, $V_{AC} = 25 mV$	
Q_{gs}	Gate to Source Charge		4	1		$V_{DS} = 1200 V, V_{GS} = -4 V/15 V$	
Q_{gd}	Gate to Drain Charge		2]	nC		
Qg	Total Gate Charge		8			Per IEC60747-8-4 pg 21	

Note (3): Co(er), a lumped capacitance that gives same stored energy as Coss while Vds is rising from 0 to 1200V Co(tr), a lumped capacitance that gives same charging time as Coss while Vds is rising from 0 to 1200V

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Reverse Diode Characteristics (T_c = 25°C unless otherwise specified)

Symbol	Parameter	Тур.	Max.	Unit	Test Conditions	Note
V _{sD} Dio	Diode Forward Voltage	4.7		V	$V_{_{GS}} = -4 V, I_{_{SD}} = 1 A, T_{_{J}} = 25 \text{ °C}$	Fig. 8,
		4.2		V	$V_{GS} = -4 \text{ V}, I_{SD} = 1 \text{ A}, T_{J} = 175 \text{ °C}$	
ls	Continuous Diode Forward Current	5.8		А	$V_{GS} = -4 V, T_C = 25^{\circ}C$	
I _{SM}	Diode pulse Current		15	А	V_{GS} = -4 V, pulse width t _P limited by T _{jmax}	
t _{rr}	Reverse Recover time	22		ns	$V_{GS} = -4 V, I_{SD} = 1.99 A, V_{R} = 1200 V$ dif/dt = 546 A/µs, T _j = 25 °C	
Q _{rr}	Reverse Recovery Charge	50		nC		
l _{rrm}	Peak Reverse Recovery Current	5		A		
t _{rr}	Reverse Recover time	28		ns		
Q _{rr}	Reverse Recovery Charge	46		nC	$V_{GS} = -4 V, I_{SD} = 1.99 A, V_{R} = 1200 V$ dif/dt = 246 A/µs, T ₁ = 25 °C	
l _{rrm}	Peak Reverse Recovery Current	3		A		

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Unit	Test Conditions	Note
R _{θJC}	Thermal Resistance from Junction to Case	3.0	3.6	°C/W		Fig. 21



Typical Performance

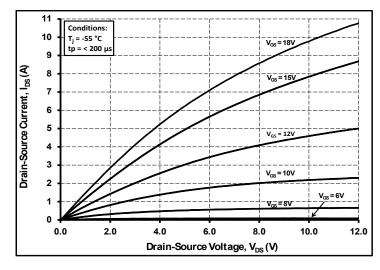


Figure 1. Output Characteristics T_J = -55 °C

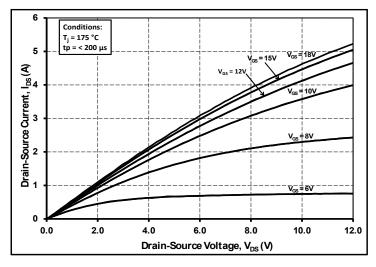


Figure 3. Output Characteristics $T_J = 175 \text{ °C}$

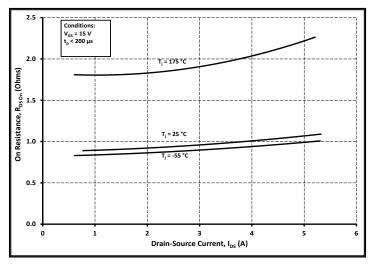
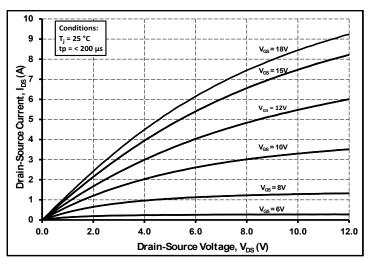


Figure 5. On-Resistance vs. Drain Current For Various Temperatures





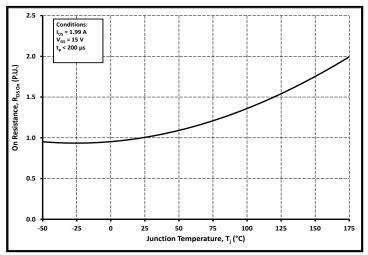


Figure 4. Normalized On-Resistance vs. Temperature

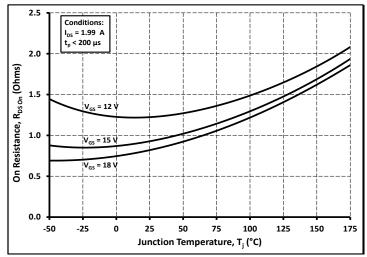
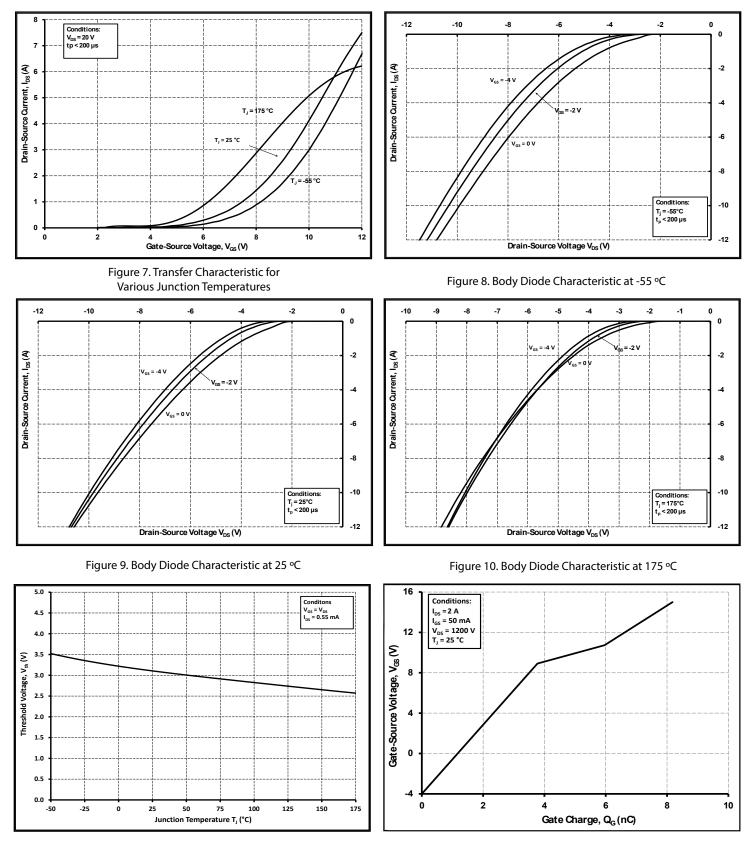


Figure 6. On-Resistance vs. Temperature For Various Gate Voltage

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Typical Performance







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Typical Performance

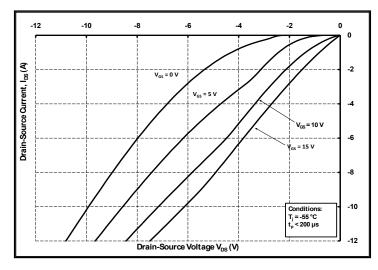


Figure 13. 3rd Quadrant Characteristic at -55 °C

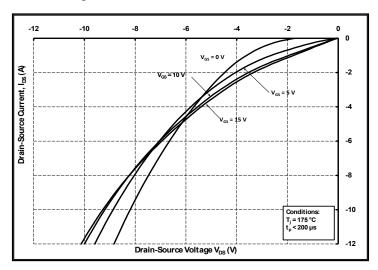
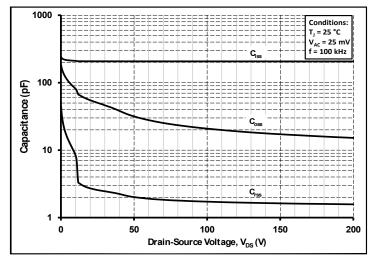
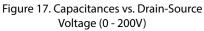


Figure 15. 3rd Quadrant Characteristic at 175 °C





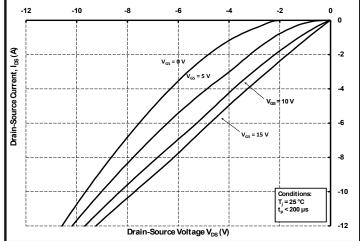


Figure 14. 3rd Quadrant Characteristic at 25 °C

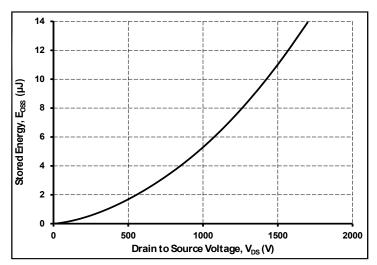


Figure 16. Output Capacitor Stored Energy

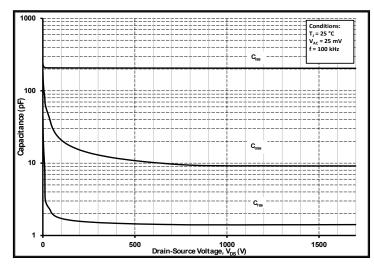


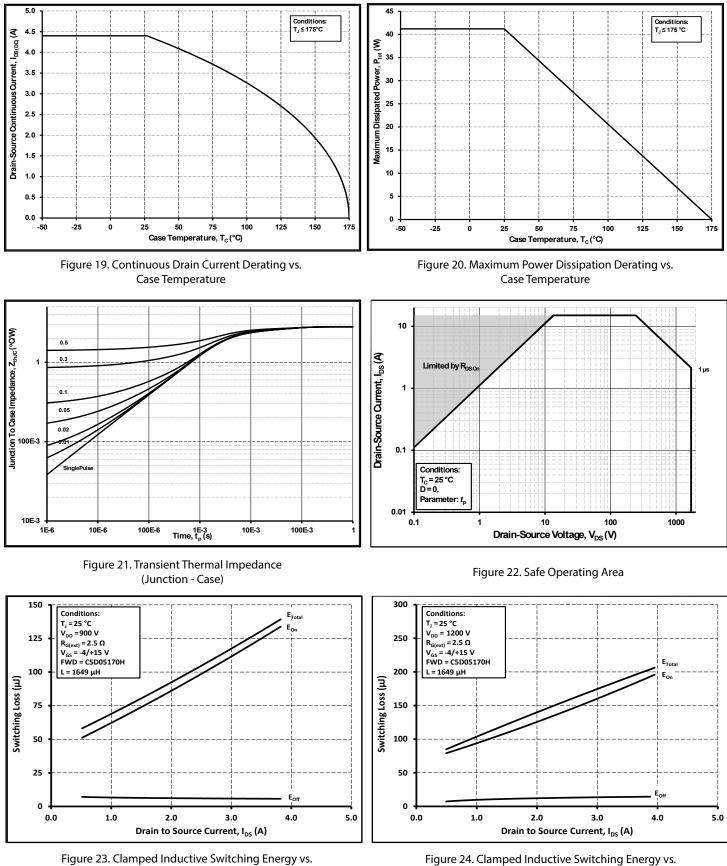
Figure 18. Capacitances vs. Drain-Source Voltage (0 - 1700V)

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Typical Performance



Drain Current (V_{DD} = 900V)

Figure 24. Clamped Inductive Switching Energy vs. Drain Current ($V_{DD} = 1200V$)

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Typical Performance

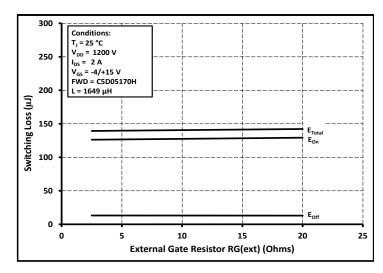


Figure 25. Clamped Inductive Switching Energy vs. $\mathrm{R}_{_{G(ext)}}$

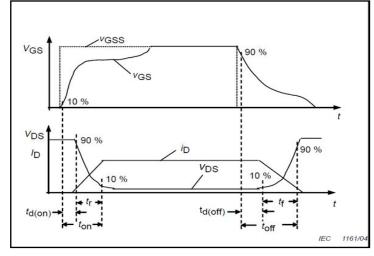


Figure 27. Switching Times Definition

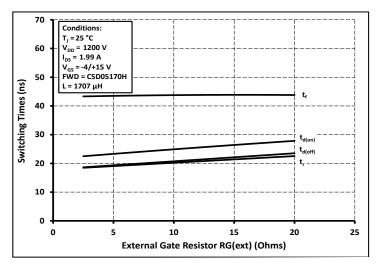
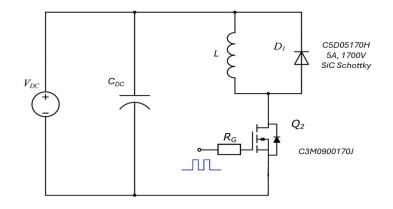
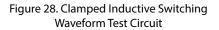


Figure 26. Switching Times vs. R_{G(ext)}

Test Circuit Schematic

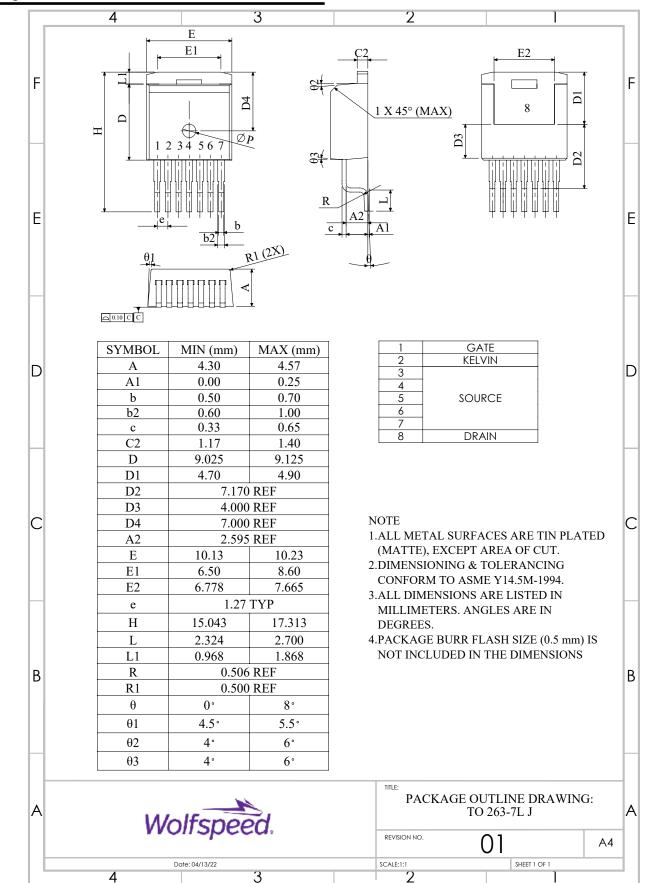






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Package Dimensions

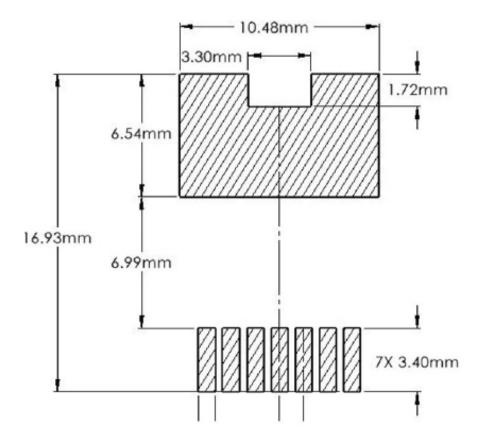


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Recommended Solder Pad Layout

All dimensions in mm



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Document Version	Date of release	Descriptiion of changes
1.0	December-2024	Initial datasheet
2.0	February-2025	Updated with latest characterization data

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